

### Dual Shapiro steps in a Josephson junctions array

Theoretical elements and experimental evidence

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## Introducing the Grenoble team This talk is presented on behalf of the Bloch Oscillations working group.



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https://arxiv.org/abs/2207.09381





Quantum Hall effect

# The fundamental units of quantum electrodynamics



<sup>1</sup>M. Tinkham - Introduction to Superconductivity

Quantum Hall effect



















- $E_J/E_C \gg 1$
- Classical (localised)  $\phi$
- Tilted washboard  $U(\phi)$
- Fluxons transport
- Shapiro steps



 $[\phi, Q] = 2ie$ 

- $E_J/E_C \sim 1$
- Classical (localised) Q
- First Bloch band U(Q)
- Cooper pairs transport
- Dual Shapiro steps



For  $E_I \simeq E_C$ , the Hamiltonian is

 $H = 4E_{\mathcal{C}} \left( Q/2e \right)^2 - E_J \cos(\phi),$ 

and can be recast to Bloch bands. If charge fluctuations are small enough, the dynamics can be restricted to the first band, obtaining

$$H = \sum_{s} U^{(s)}(q) \sim E_Q \cos(\pi Q/e).$$























We first devise a scheme that satisfies the theoretical constraints.

Theory

- Bloch bands dynamics
- Localised charge wavefunction
- Negligible thermal fluctuations

Experiment

- Ultrasmall junction,  $E_J/E_{\mathcal{C}}\simeq 1$
- Environmental impedance  $> R_q$
- Low temperatures,  $T \simeq 20 \, {
  m mK}$



Ultrasmall JJs 📃 Superinductances

Guichard and Hekking, Phys. Rev. B 81 (2010) + Arndt, Roy, and Hassler Phys. Rev. B 98 (2018)



The devices are patterned in a single lithographic step, and to reduce ground capacitances we employ a low- $\epsilon$  fused-silica wafer.



#### Additional parameters for number crunchers

Ultrasmall junction:  $E_J/E_C = 1.6$ ,  $E_Q \simeq 2.5$  GHz,  $\Delta U \simeq 7.9$  GHz,  $I_c \simeq 10$  nA Superinductances:  $Z_a = 8.0$  k $\Omega$ ,  $L_a = 3.3 \mu$ H,  $E_J/E_C = 250$ ,  $N_a = 1750$ 

## VEEL Down to a measurement setup

Our experimental apparatus allows for simultaneous DC and microwave measurements.



- Low noise RF and DC lines
- Off-chip resistors and bias-tees
- 23 mK working temperature
- Qcodes DAQ



Time to measure!

**IV characteristics** Probing the current flowing through the device with a low applied voltage.



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A toy model of the Bloch array RCSJ simulations confirm the consistency of what we experimentally observe.

$$V = L\ddot{Q} + R\dot{Q} + V_c \sin\left(\frac{\pi}{e}Q\right) + \sum_i \dot{\phi}_i$$



**A toy model of the Bloch array** We push the model a bit further to know what to expect.

$$V + V_{\mathrm{ac}} = L\ddot{Q} + R\dot{Q} + V_c\sin\left(\frac{\pi}{e}Q\right) + \sum_i \dot{\phi}_i$$





#### Symmetry matters

The odd modes of the array are coupled to the center, i.e. to the ultrasmall junction.

Léger, Roch *et al*. Nat.Comm. 2019 arxiv.org/abs/1910.08340



## Microwave properties with tone irradiation

We observe the emergence of a mode synchronous with the tone.



#### Why is synchronicity relevant?

Bloch oscillations are the phenomenon dual to the AC Josephson effect which need to synchronise to the external tone in order to give steps.



#### We measure the IV curve with the tone parameters of the Bloch mode.



IV characteristic under microwave irradiation

With f = 4.04 GHz and p = -5.0 dBm, we get plateaux of current 2*ef* before every peak.



The power dependence of the step is studied by measuring the step current as a function of the pump power, and by modulating the pump amplitude.



Both the measurements indicate that at the power where we observe the Bloch mode there is a singularity of the system.

### Frequency dependence of the current plateaux

Using different array modes we verify the expected scaling of current vs. frequency.

#### Metrology

The measurement of the step current  $2e \cdot f$  at different f relates frequency to current through the Cooper pair charge 2e. This can be used to get a quantum metrological definition of the Ampére.





#### Bloch array with microwaves OFF

- Observation and modelisation of  $2\Delta$ -spaced peaks
- Characterisation of the microwave dynamics
- Simultaneous DC and microwave study of the sample

#### Bloch array with microwaves ON

- Detection of a microwave mode synchronous with the tone
- Corresponding emergence of flat 2*ef* current plateaux in the IV curve
- Same phenomenology observed at four different frequencies

#### What's next?

After this first evidence, the phenomenon needs to be studied. A systematic analysis of the various parameters will allow to master the Bloch array and improve it. Plus: there are many interesting behaviours of the device which are currently under study.

Preprint online: https://arxiv.org/abs/2207.09381



## Thank you for your time!

https://arxiv.org/abs/2207.09381 - nicolo.crescini@neel.cnrs.fr

## **VEEL** Backup slide 1: microwave spectroscopy with DC bias

We measure the GHz-frequency properties of the sample with a DC bias.



## **Backup slide 2: modes used for the steps** The central junction is a SQUID.



Backup slide 3b: power dependence

Full steps IV as a function of the tone's power.

The effect of higher power is to gradually reduce the peaks height, and therefore the step, starting from the one closer to zero voltage.

#### On the to-do list

This observation suggests that it would be better to observe the same effects with lower power, not to compromise the array's properties.



## **Backup slide 4a: flux dependence** The central junction is a SQUID, so we expect some flux dependence.



Hofstadter's butterfly?









## Backup slide 5: two-tones spectroscopy We use two-tones spectroscopy to characterise the FSR and plasma frequency of the array.





The IV curve is the numerical simulation of a Bloch array comprising:

- $N \times \text{RCSJ}$  junctions in series
- non-linear capacitor  $V_c$

#### Total current though each junction

where  $\phi_i$  is the superconducting phase drop on the  $i^{\rm th}$  junction.

$$\begin{split} I_{\text{tot}} &= I_{C} + I_{R} + I_{J} \\ I_{C} &= C\ddot{\phi}_{i}, \\ I_{R} &= s(\dot{\phi}_{i})\frac{1}{R_{N}}\dot{\phi}_{i}, \\ I_{J} &= \left(1 - s(\dot{\phi}_{i})\right)I_{c}\sin\left(\frac{\phi_{i}}{\phi_{0}}\right). \end{split}$$
(1)

- an inductance L
- a damping resistor R

#### And we solve the equation of motion

$$V = L\ddot{Q} + R\dot{Q} + V_c \sin\left(\frac{\pi}{e}Q\right) + \sum_i \dot{\phi}_i$$

#### With the following parameters

- N = 4
- dt = 0.02 RC
- $L = 5 \,\mu \mathrm{H}$

- $R = 1 \,\mathrm{k}\Omega$
- $V_c \simeq 50 \,\mu V$